

# Telemaco3P

## Automotive Processor for Secure Telematics and Connectivity



The rising demand for data connectivity, cybersecurity and over-the-air updates of in-vehicle control units requires more processing power and uncompromised cybersecurity.

ST's Telemaco3P system-on-chip provides a cost-effective solution for ensuring a secure connection between the vehicle and the cloud. Its asymmetric multi-core architecture provides powerful application processors as well as an independent CAN control subsystem with optimized power management. Its ISO 26262 silicon design, its embedded Hardware Security Module and automotive-grade qualification up to 105 °C ambient temperature, make it the best candidate for implementing a wide range of secure telematics applications supporting high-throughput wireless connectivity and over-the-air firmware upgrades.

### KEY FEATURES

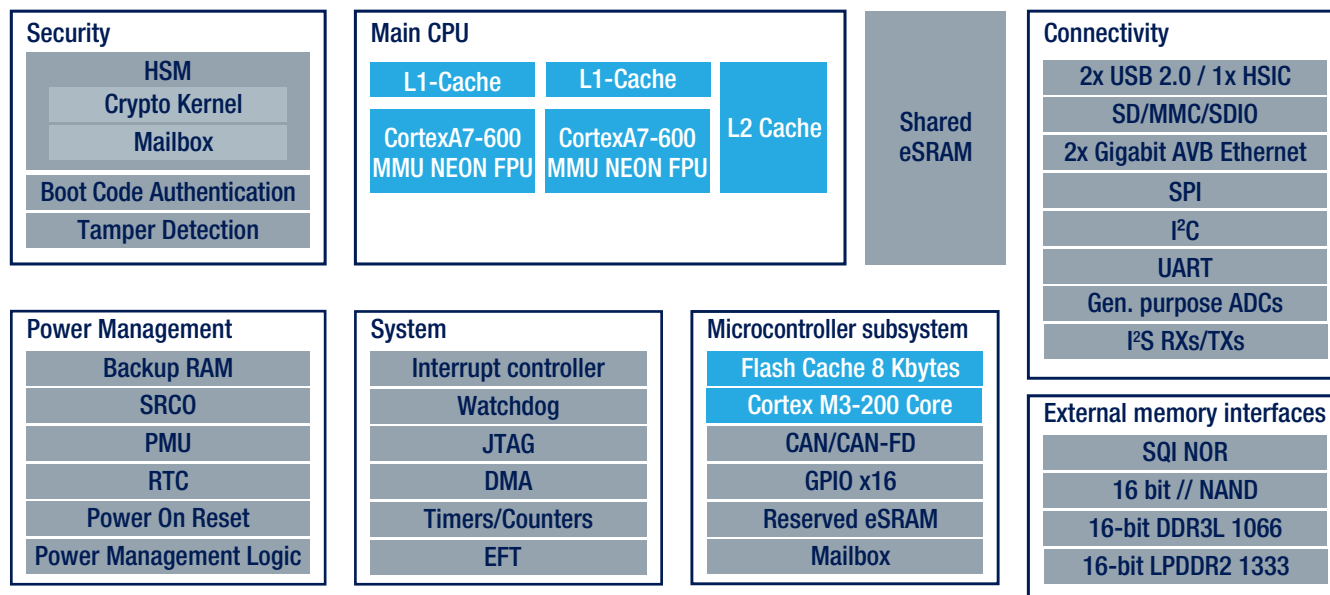
- Single or dual ARM Cortex A7 at 600 MHz (up to 2400 DMIPS)
- Embedded HSM implementing SHE+ extended specification
- Independent and isolated CAN subsystem on embedded ARM Cortex M3 with reserved eSRAM, running its dedicated RTOS
- 2 Gigabit Ethernet with AVB
- Multiple USB 2.0, SD/SDIO, CAN/CAN-FD, SPI, I<sup>2</sup>C, UART
- ASIL-B eligible
- Operating temperature range: -40 to +105 °C
- Integrated power management logic
- Power consumption in Standby: 20 µA
- Wake-up time < 50 ms

### SOFTWARE OFFERING

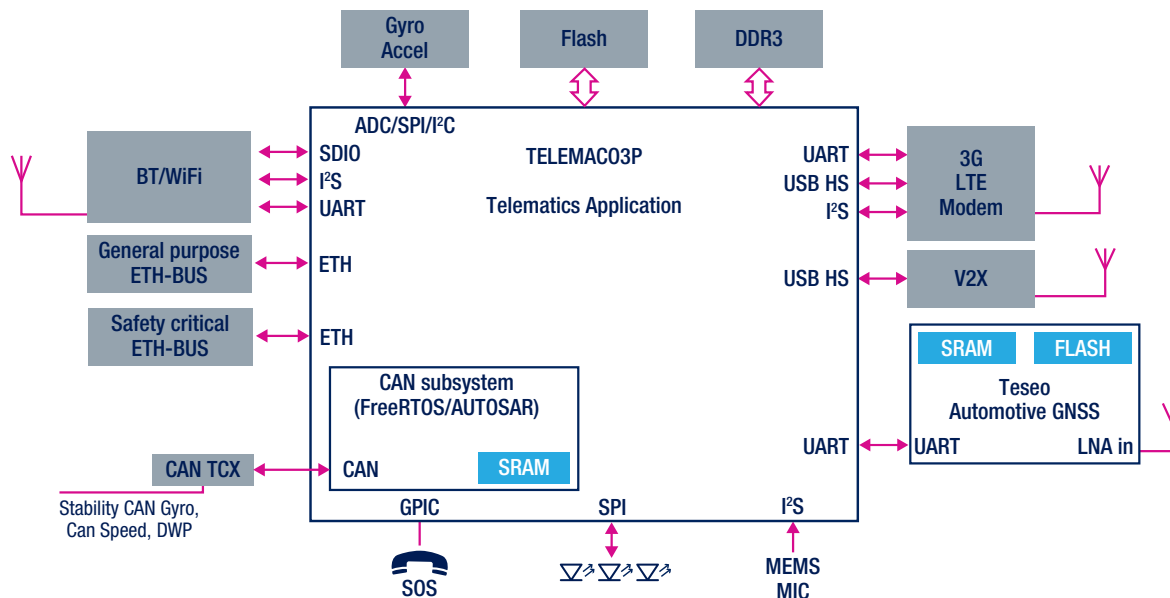
- OS kernel and BSP: Linux / QNX
- Standard Yocto tools
- Pre-integrated open-source & 3rd party middleware for easy implementation
- Distributed RPMmsg framework for secure inter process communication
- Bootloader toolset for custom / smart boot implementations
- FreeRTOS kernel and MCAL for AUTOSAR 4.2 on Cortex M3
- 3rd party support of Adaptive AUTOSAR on Cortex A7 cluster



# TELEMAC03P BLOCK DIAGRAM



## EXAMPLE SOLUTION



Part number	A7 cores	Memory Width
STA1375	1	16-bit
STA1385	2	16-bit

### OPERATING CONDITIONS

- ARM\_VDD: 1.14V to 1.26V
- VDD\_IO\_3V3: 3.3V ±10%
- VDD\_IO\_1V8: 1.8V ±10%
- VDDQ (DDR3): 1.35V ± 5%
- Operating temperature: -40/+105°C
- Automotive AEC-Q100 Grade 2 compliance

### PACKAGE INFORMATION

- 361-ball LFBGA (16 x 16 x 1.7 mm) package with 0.8 mm pitch

